## 捷多邦,专业PCB打样工厂,24/J SN74LV CH322244A 32-BIT BUFFER/DRIVER WITH 3-STATE OUTPUTS

SCES405B-JULY 2002-REVISED APRIL 2005

#### **FEATURES**

- Member of the Texas Instruments Widebus+™
   Family
- Operates From 1.65 V to 3.6 V
- Inputs Accept Voltages to 5.5 V
- Max t<sub>pd</sub> of 4.4 ns at 3.3 V
- Output Ports Have Equivalent 26-Ω Series Resistors, So No External Resistors Are Required
- Typical V<sub>OLP</sub> (Output Ground Bounce)
   0.8 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C
- Typical V<sub>OHV</sub> (Output V<sub>OH</sub> Undershoot)
   2 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C

- I<sub>off</sub> Supports Partial-Power-Down Mode Operation
- Supports Mixed-Mode Signal Operation
   On All Ports (5-V Input/Output Voltage With 3.3-V V<sub>CC</sub>)
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)

### **DESCRIPTION/ORDERING INFORMATION**

This 32-bit buffer/driver is designed for 1.65-V to 3.6-V V<sub>CC</sub> operation.

The SN74LVCH322244A is designed specifically to improve the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters.

The device can be used as eight 4-bit buffers, four 8-bit buffers, two 16-bit buffers, or one 32-bit buffer. It provides true outputs and symmetrical active-low output-enable (OE) inputs.

Inputs can be driven from either 3.3-V or 5-V devices. This feature allows the use of these devices as translators in a mixed 3.3-V/5-V system environment.

The outputs, which are designed to sink up to 12 mA, include equivalent 26- $\Omega$  resistors to reduce overshoot and undershoot.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Active bus-hold circuitry holds unused or undriven inputs at a valid logic state. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

This device is fully specified for partial-power-down applications using I<sub>off</sub>. The I<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

### ORDERING INFORMATION

T <sub>A</sub>	PACKAGE <sup>(1)</sup>		ORDERABLE PART NUMBER	TOP-SIDE MARKING
40°C to 05°C	LFBGA – GKE	Tone and real	SN74LVCH322244AKR	- CG244A
-40°C to 85°C	LFBGA – ZKE (Pb-free)	Tape and reel	74LVCH322244AZKER	CG244A

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

# FUNCTION TABLE (EACH 4-BIT BUFFER)

INPU	JTS	OUTPUT
ŌĒ	Α	Y
L	Н	Н
L	L	L
Н	X	Z

PDRease be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

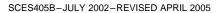


# GKE OR ZKE PACKAGE (TOP VIEW)

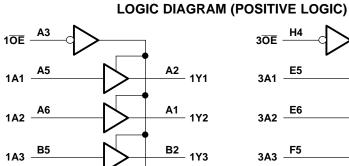
1 2 3 4 5 6 000000 Α 000000 В 000000 С D 000000 000000 Ε 000000 F 000000 G 000000 Н 000000 J 000000 Κ 000000 L 000000 М 000000 Ν 000000 Ρ 000000 R 000000 Т

#### **TERMINAL ASSIGNMENTS**

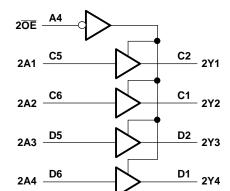
	1	2	3	4	5	6
Α	1Y2	1Y1	1 <del>OE</del>	2 <del>OE</del>	1A1	1A2
В	1Y4	1Y3	GND	GND	1A3	1A4
С	2Y2	2Y1	V <sub>CC</sub>	$V_{CC}$	2A1	2A2
D	2Y4	2Y3	GND	GND	2A3	2A4
Е	3Y2	3Y1	GND	GND	3A1	3A2
F	3Y4	3Y3	V <sub>CC</sub>	$V_{CC}$	3A3	3A4
G	4Y2	4Y1	GND	GND	4A1	4A2
Н	4Y3	4Y4	4 <del>OE</del>	3 <del>OE</del>	4A4	4A3
J	5Y2	5Y1	5 <del>OE</del>	6 <del>0E</del>	5A1	5A2
K	5Y4	5Y3	GND	GND	5A3	5A4
L	6Y2	6Y1	V <sub>CC</sub>	$V_{CC}$	6A1	6A2
М	6Y4	6Y3	GND	GND	6A3	6A4
N	7Y2	7Y1	GND	GND	7A1	7A2
Р	7Y4	7Y3	V <sub>CC</sub>	$V_{CC}$	7A3	7A4
R	8Y2	8Y1	GND	GND	8A1	8A2
Т	8Y3	8Y4	8 <del>0E</del>	7 <del>0E</del>	8A4	8A3



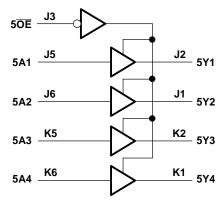


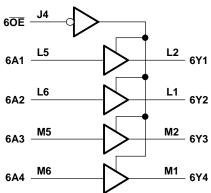


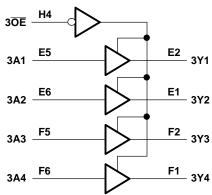
B1 1Y4

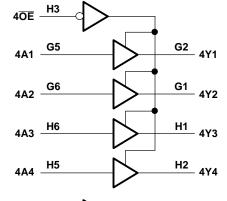


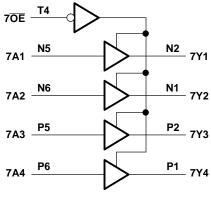
1A4 B6

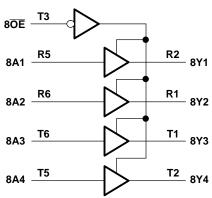












## SN74LVCH322244A 32-BIT BUFFER/DRIVER WITH 3-STATE OUTPUTS

SCES405B-JULY 2002-REVISED APRIL 2005



### Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
$V_{CC}$	V <sub>CC</sub> Supply voltage range				V
$V_{I}$	Input voltage range <sup>(2)</sup>		-0.5	6.5	V
Vo	Voltage range applied to any output in the high-impo	edance or power-off state <sup>(2)</sup>	-0.5	6.5	V
Vo	V <sub>O</sub> Voltage range applied to any output in the high or low state (2)(3)				V
I <sub>IK</sub>	Input clamp current V <sub>I</sub> < 0			-50	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		-50	mA
IO	Continuous output current			±50	mA
	Continuous current through each V <sub>CC</sub> or GND			±100	mA
$\theta_{JA}$	Package thermal impedance <sup>(4)</sup>	GKE/ZKE package		40	°C/W
T <sub>stg</sub>	Olympia to the properties are the			150	°C

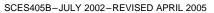
<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating" conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.
- The value of  $V_{CC}$  is provided in the recommended operating conditions table. The package thermal impedance is calculated in accordance with JESD 51-7.

## **Recommended Operating Conditions**(1)

			MIN	MAX	UNIT
V	Complementaria	Operating	1.65	3.6	V
$V_{CC}$	Supply voltage	Data retention only	1.5		V
		V <sub>CC</sub> = 1.65 V to 1.95 V	0.65 × V <sub>CC</sub>		
$V_{IH}$	High-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$			V
		V <sub>CC</sub> = 2.7 V to 3.6 V	2		
		V <sub>CC</sub> = 1.65 V to 1.95 V		0.35 × V <sub>CC</sub>	
$V_{IL}$	Low-level input voltage	V <sub>CC</sub> = 2.3 V to 2.7 V		0.7	V
		V <sub>CC</sub> = 2.7 V to 3.6 V		0.8	
$V_{I}$	Input voltage	·	0	5.5	V
V	Output wellians	High or low state	0	V <sub>CC</sub>	V
$V_{O}$	Output voltage	3-state	0	5.5	V
		V <sub>CC</sub> = 1.65 V		-2	
	High laved autout average	V <sub>CC</sub> = 2.3 V		-4	A
I <sub>OH</sub>	High-level output current	V <sub>CC</sub> = 2.7 V		-8	mA
		V <sub>CC</sub> = 3 V		-12	
		V <sub>CC</sub> = 1.65 V		2	
	Lavidaval autout avenue	V <sub>CC</sub> = 2.3 V		4	A
I <sub>OL</sub>	Low-level output current	V <sub>CC</sub> = 2.7 V		8	mA
		V <sub>CC</sub> = 3 V		12	
Δt/Δν	Input transition rise or fall rate	,		10	ns/V
T <sub>A</sub>	Operating free-air temperature		-40	85	°C

All unused control inputs of the device must be held at  $V_{CC}$  or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.





### **Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS		V <sub>CC</sub>	MIN	TYP <sup>(1)</sup> MAX	UNIT
	I <sub>OH</sub> = -100 μA		1.65 V to 3.6 V	V <sub>CC</sub> - 0.2		
	$I_{OH} = -2 \text{ mA}$		1.65 V	1.2		
	$I_{OH} = -4 \text{ mA}$		2.3 V	1.7		
V <sub>OH</sub>	I <sub>OH</sub> = -4 IIIA	2.7 V	2.2		V	
	$I_{OH} = -6 \text{ mA}$		3 V	2.4		
	$I_{OH} = -8 \text{ mA}$		2.7 V	2		
	$I_{OH} = -12 \text{ mA}$		3 V	2		
	$I_{OL} = 100 \mu A$		1.65 V to 3.6 V		0.2	
	I <sub>OL</sub> = 2 mA		1.65 V		0.45	
	l = 4 mΛ		2.3 V		0.7	
$V_{OL}$	$I_{OL} = 4 \text{ mA}$		2.7 V		0.4	V
	I <sub>OL</sub> = 6 mA		3 V		0.55	
	$I_{OL} = 8 \text{ mA}$		2.7 V		0.6	
	I <sub>OL</sub> = 12 mA		3 V		0.8	
I <sub>I</sub>	$V_I = 0 \text{ to } 5.5 \text{ V}$		3.6 V		±5	μΑ
	V <sub>I</sub> = 0.58 V		1.65 V	(2)		
	V <sub>I</sub> = 1.07 V		1.03 V	(2)		
	$V_1 = 0.7 V$		2.3 V	45		
I <sub>I(hold)</sub>	V <sub>I</sub> = 1.7 V		2.3 V	-45		μΑ
	$V_1 = 0.8 \ V$		3 V	75		
	V <sub>I</sub> = 2 V		3 V	<b>–</b> 75		
	$V_I = 0$ to 3.6 $V^{(3)}$		3.6 V		±500	
I <sub>off</sub>	$V_I$ or $V_O = 5.5 \text{ V}$		0		±10	μΑ
$I_{OZ}$	V <sub>O</sub> = 0 to 5.5 V		3.6 V		±10	μΑ
	$V_I = V_{CC}$ or GND	I <sub>O</sub> = 0	3.6 V		40	μΑ
I <sub>cc</sub>	$3.6 \text{ V} \le V_1 \le 5.5 \text{ V}^{(4)}$	10 = 0	3.0 V		40	μΑ
Δl <sub>CC</sub>	One input at $V_{CC}$ – 0.6 V, Other inputs at $V_{CC}$ or GND		2.7 V to 3.6 V		500	μΑ
C <sub>i</sub>	$V_I = V_{CC}$ or GND		3.3 V		5.5	pF
C <sub>o</sub>	$V_O = V_{CC}$ or GND		3.3 V		6	pF

- All typical values are at  $V_{CC}$  = 3.3 V,  $T_A$  = 25°C. This information was not available at the time of publication.
- This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.
- This applies in the disabled state only.

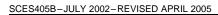
### **Switching Characteristics**

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC} = 1.8 \text{ V} $ $V_{CC} = 2.5 \text{ V} $ $V_{CC} = 2.7 \text{ V} $ $V_{CC} = 3.3 \text{ V} $		V <sub>CC</sub> = 2.7 V		3.3 V 3 V	UNIT			
	(INFOT)	(001F01)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t <sub>pd</sub>	Α	Y	(1)	(1)	(1)	(1)	1	5.6	1.1	4.4	ns
t <sub>en</sub>	ŌĒ	Υ	(1)	(1)	(1)	(1)	1	6.9	1	5.5	ns
t <sub>dis</sub>	ŌĒ	Y	(1)	(1)	(1)	(1)	1	6.8	1.8	6.3	ns

<sup>(1)</sup> This information was not available at the time of publication.

# SN74LVCH322244A 32-BIT BUFFER/DRIVER WITH 3-STATE OUTPUTS





## **Operating Characteristics**

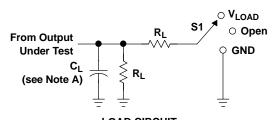
 $T_A = 25^{\circ}C$ 

	PARAMETER			V <sub>CC</sub> = 1.8 V TYP	V <sub>CC</sub> = 2.5 V TYP	V <sub>CC</sub> = 3.3 V TYP	UNIT
	Power dissipation capacitance	Outputs enabled	f 10 MHz	(1)	(1)	35	"F
C <sub>pd</sub>	C <sub>pd</sub> per buffer/driver Outputs disc		f = 10 MHz	(1)	(1)	4	pF

<sup>(1)</sup> This information was not available at the time of publication.



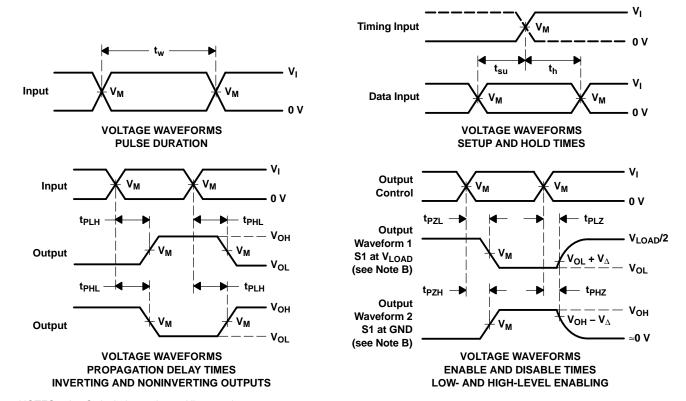
### PARAMETER MEASUREMENT INFORMATION



TEST	S1
t <sub>PLH</sub> /t <sub>PHL</sub> t <sub>PLZ</sub> /t <sub>PZL</sub> t <sub>PHZ</sub> /t <sub>PZH</sub>	Open V <sub>LOAD</sub> GND

LUAD	CIRCUIT

.,	INF	PUTS	.,	.,			.,
V <sub>CC</sub>	VI	t <sub>r</sub> /t <sub>f</sub>	V <sub>M</sub>	V <sub>LOAD</sub>	CL	$R_L$	$oldsymbol{V}_\Delta$
1.8 V $\pm$ 0.15 V	ν <sub>cc</sub>	≤2 ns	V <sub>CC</sub> /2	2×V <sub>CC</sub>	30 pF	<b>1 k</b> Ω	0.15 V
2.5 V $\pm$ 0.2 V	$v_{cc}$	≤2 ns	V <sub>CC</sub> /2	2×V <sub>CC</sub>	30 pF	500 $\Omega$	0.15 V
2.7 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	500 $\Omega$	0.3 V
3.3 V $\pm$ 0.3 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	500 $\Omega$	0.3 V



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ .
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t<sub>PLZ</sub> and t<sub>PHZ</sub> are the same as t<sub>dis</sub>.
- F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
- G. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>pd</sub>.
- H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms



### PACKAGE OPTION ADDENDUM

30-Mar-2005

### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
74LVCH322244AZKER	ACTIVE	LFBGA	ZKE	96	1000	Green (RoHS & no Sb/Br)	SNAGCU	Level-3-250C-168 HR
SN74LVCH322244AKR	ACTIVE	LFBGA	GKE	96	1000	TBD	SNPB	Level-3-220C-168 HR

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check <a href="http://www.ti.com/productcontent">http://www.ti.com/productcontent</a> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

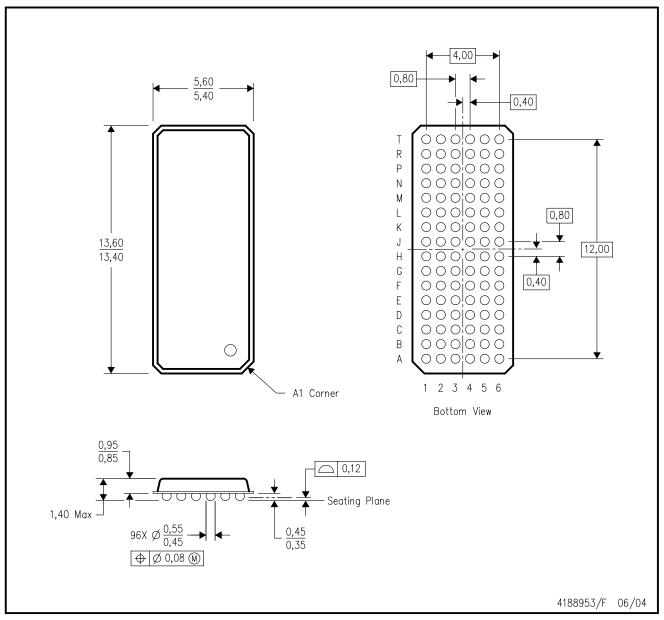
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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# GKE (R-PBGA-N96)

# PLASTIC BALL GRID ARRAY



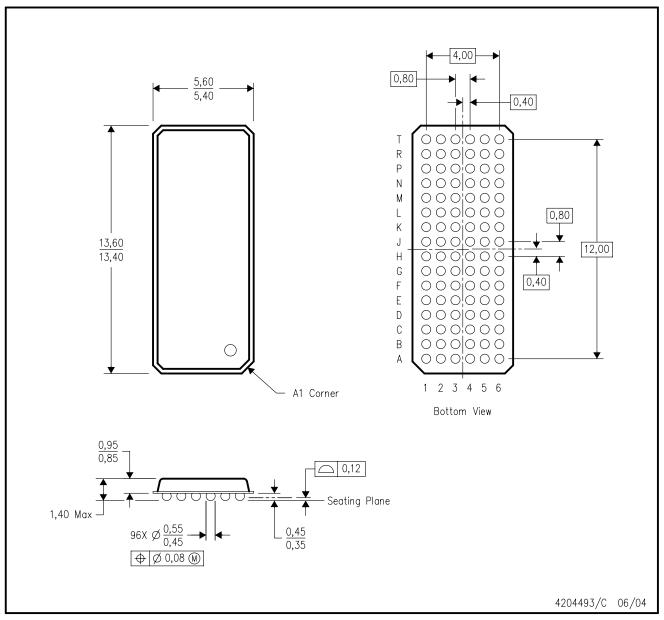
NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-205 variation CC.
- D. This package is tin-lead (SnPb). Refer to the 96 ZKE package (drawing 4204493) for lead-free.



# ZKE (R-PBGA-N96)

# PLASTIC BALL GRID ARRAY



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-205 variation CC.
- D. This package is lead—free. Refer to the 96 GKE package (drawing 4188953) for tin—lead (SnPb).



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